

20V PNP HIGH GAIN TRANSISTOR PowerDI[®]5

Features

- 43% smaller than SOT223; 60% smaller than TO252
- Maximum height just 1.1mm
- Rated up to 1.3W
- $V_{CEO} = -20V$
- $I_C = -8A$; $I_{CM} = -15A$
- Low Saturation voltage, high gain transistor
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Applications

- Load disconnect switch
- Battery charging

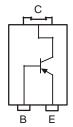
Mechanical Data

- Case: PowerDI®5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.093 grams (approximate)









Top View

Bottom View

Device Schematic

Pin-out diagram

Ordering Information (Note 3)

ſ	Part Number	Case	Packaging
	DXTP19020DP5-13	PowerDI [®] 5	5000/Tape & Reel

Notes:

- 1. No purposefully added lead. Halogen and Antimony Free.
- 2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com 3. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



DTP1920D = Product Type Marking Code Oll = Manufacturers' Code Marking K = Factory Designator YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 09 for 2009) WW = Week code (01 to 53)



Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-25	V
Collector-Emitter Voltage	V _{CEO}	-20	V
Emitter-Collector Voltage (Reverse Blocking)	V _{ECO}	-4	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	I _C	-8	A
Base Current	I _B	-1	A
Peak Pulse Current	I _{CM}	-15	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation @ T _A = 25°C (Note 4)	P_{D}	1.3	W
Thermal Resistance, Junction to Ambient Air (Note 4) @T _A = 25°C	$R_{ heta JA}$	96.1	°C/W
Power Dissipation @ T _A = 25°C (Note 5)	P_{D}	3	W
Thermal Resistance, Junction to Ambient Air (Note 5) @T _A = 25°C	$R_{ heta JA}$	41.7	°C/W
Operating and Storage Temperature Range	TJ, T _{STG}	-55 to +150	°C

Notes:

Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-25	-55		٧	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 6)	$V_{(BR)CEO}$	-20	-50	_	V	I _C = -10mA
Emitter-Collector Breakdown Voltage (Reverse Blocking)	V _{(BR)ECX}	-4	-8.6		>	I_E = -100μA, R_{BC} < 1k Ω or 0.25V > V_{CB} > -0.25V
Emitter-Base Breakdown Voltage (Reverse Blocking)	V _{(BR)ECO}	-4	-8.6		٧	$I_E = -100 \mu A$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-7	-8.2		٧	$I_E = -100 \mu A$
Collector Cutoff Current	I _{CBO}	_	<1 —	50 0.5	nA μA	V _{CB} = -25V V _{CB} = -25V, T _{amb} = 100 °C
Emitter Cutoff Current	I _{EBO}	_	<1	-50		V _{EB} = -5.6V
Collector-Emitter Saturation Voltage (Note 6)	V _{CE(sat)}	_	-40 -97 -115 -220	-47 -130 -145 -275	mV	I _C = -1A, I _B = -100mA I _C = -1A, I _B = -10mA I _C = -2A, I _B = -40mA I _C = -8A, I _B = -800mA
Base-Emitter Saturation Voltage (Note 6)	V _{BE(sat)}	_	-1050	-1150	mV	I _C = -8A, I _B = -800mA
Base-Emitter Turn-On Voltage (Note 6)	V _{BE(on)}	_	-930	-1000	mV	$I_{C} = -8A, V_{CE} = -2V$
DC Current Gain (Note 6)	h _{FE}	300 200 45 —	450 290 70 25	900 — — —		I _C = -100mA, V _{CE} = -2V I _C = -2A, V _{CE} = -2V I _C = -8A, V _{CE} = -2V I _C = -15A, V _{CE} = -2V
Transition Frequency	f _T	_	176	١	MHz	$I_C = -50 \text{mA}, V_{CE} = -10 \text{V},$ f = 50MHz
Input Capacitance (Note 6)	C_{ibo}	_	_	400	pF	$V_{EB} = -0.5V, f = 1MHz$
Output Capacitance (Note 6)	C_{obo}	_	36	45	pF	$V_{CB} = -10V$, $f = 1MHz$
Delay Time	t _d	_	23			
Rise Time	t _r	_	18.4	_	ns	$I_C = -1A$, $V_{CC} = -10V$,
Storage Time	ts	_	266		115	$I_{B1} = -I_{B2} = -50 \text{mA}$
Fall Time	t _f	_	49.6	_		

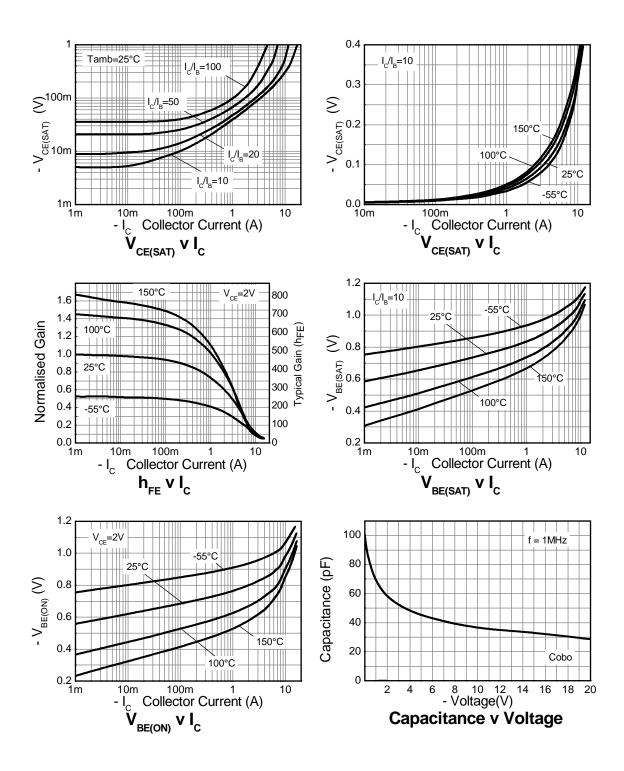
Notes: 6. Pulse Test: Pulse width ${\leq}300\mu s.$ Duty cycle ${\leq}2.0\%.$

^{4.} Device mounted on FR-4 PCB, 2 oz. copper, minimum recommended pad layout. 5. Device mounted on FR-4 PCB, 2 oz. copper, collector pad dimensions 0.42inch².



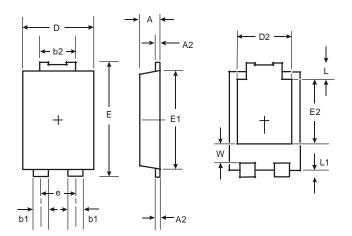


Typical Characteristic



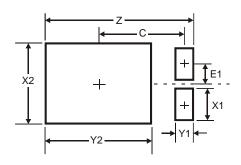


Package Outline Dimensions



PowerDI [®] 5				
Dim	Min	Max		
Α	1.05	1.15		
A2	0.33	0.43		
b1	0.80	0.99		
b2	1.70	1.88		
D	3.90 4.05			
D2	3.054 Typ			
Е	6.40	6.60		
е	1.84 Typ			
E1	5.30 5.45			
E2	3.549 Typ			
L	0.75	0.95		
L1	0.50 0.65			
W	W 1.10 1.41			
All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)
Z	6.6
X1	1.4
X2	3.6
Y1	0.8
Y2	4.7
С	3.87
F1	0.9





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